NSN 5961-01-088-6022

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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.500 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

225.0 collector to base voltage, dc and 200.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 3.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

44.00 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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